

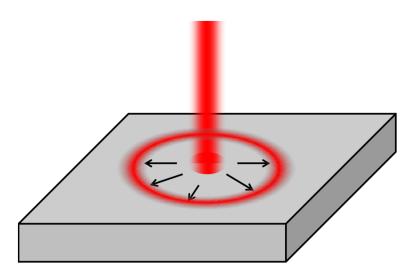
Outline

- Measurement of lateral heat flow: thin metal films, anisotropic crystals
- Non-equilibrium between excitations: electronphonon, magnon-phonon, phonon-phonon
- Alternatives to conventional thermoreflectance for ultrafast thermometry
 - Transient absorption using plasmon resonances in Au nanostructures
 - Time-resolved magneto-optic Kerr effect (TR-MOKE) of thin film perpendicular magnets.

Lateral heat flow

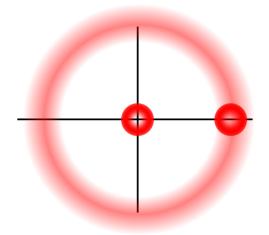
- TDTR is typically only sensitive to heat flow normal to the surface because the spot radius is large compared to the thermal penetration depth, i.e., $|q|w_0 \gg 1$
- Points toward using low modulation frequency and small spot sizes but there are tough limits
 - Repetition time of laser is $\tau_{\rm rep}{=}12.5$ ns. If $f\tau_{\rm rep}{\,\ll\,}1$ sensitivity can suffer
 - Need to avoid clipping of probe so hard to get w_0 <1 µm.
- Can we improve the experiment by offsetting the pump and probe? Yes, in some cases.
- Sensitivity can also be enhanced if the layer under study is thermally thin and placed on a low thermal conductivity substrate

In-plane thermal conductivity using TDTR with offset laser beams



$$\Delta T(f) = \frac{2\pi}{A_S} \int_0^\infty G(f, k) P(k) S(k) k \, dk$$

The only difference from normal TDTR!



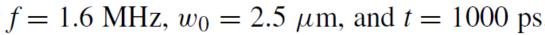
$$\frac{2A_S}{\pi w_S^2} \exp\left(-\frac{2\left[(x-x_0)^2+y^2\right]}{w_S^2}\right) \left(\frac{2A_S}{\pi w_S^2}\right) \exp\left(-\frac{2(r^2+x_0^2)}{w_S^2}\right) I_0\left(\frac{4x_0r}{w_S^2}\right)$$

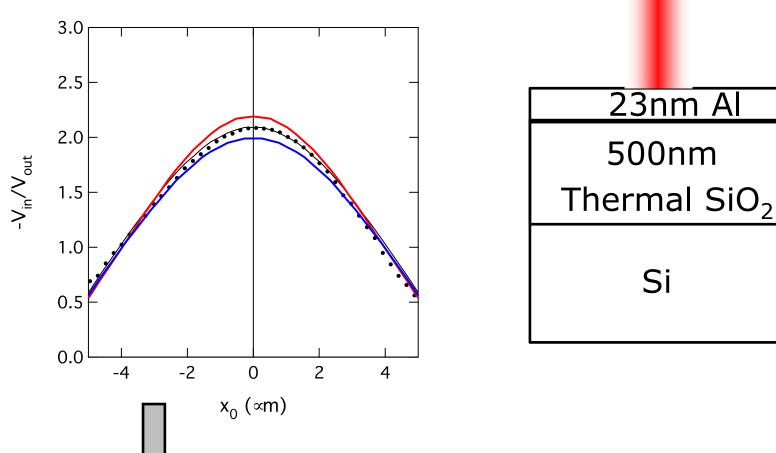
Offset Gaussian Intensity

Distributed Ring Intensity

J.P. Feser, D.G. Cahill, Rev. Sci. Instr., 83, 104901 (2012).

For Al, electronic thermal conductivity should dominate; measured Λ is in agreement with W-F





 $\Lambda_{\parallel} = 120 \text{ W/m-K} (\Lambda_{W-F} = 132 \text{ W/m-K})$

Pushing the sensitivity requires smaller spot size and a low thermal conductivity substrate

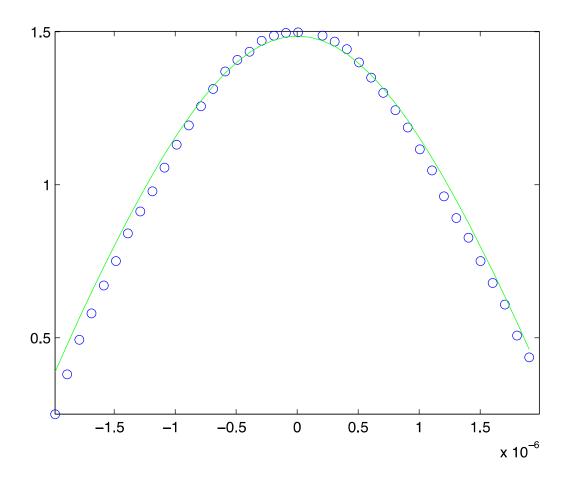
• In most cases, the relevant parameter is the lateral conductance of the film $h\Lambda$, h layer thickness, Λ in-plane thermal conductivity

$$V(32 \text{ nm})/BK7$$

 $w_0 = 1.05 \mu \text{m}$

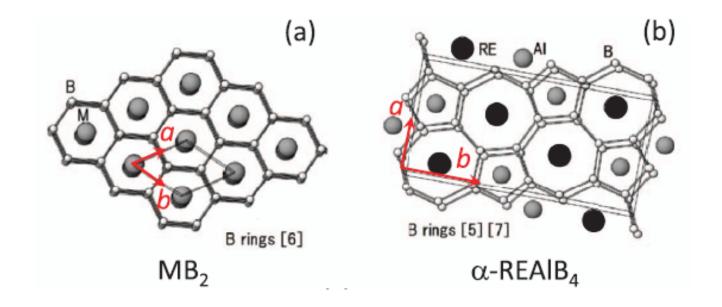
$$\Lambda = 14.5 \text{ W m}^{-1} \text{ K}^{-1}$$

 $\Lambda_{el} = 15.0 \text{ W m}^{-1} \text{ K}^{-1}$



Thermal conductivity of hexagonal borides

- Collaboration with T. Mori (NIMS)
- Compare AlB₂ (metallic) and TmAlB₄ (semi-metal)
- Cleave small crystals (flakes) along the basal plane

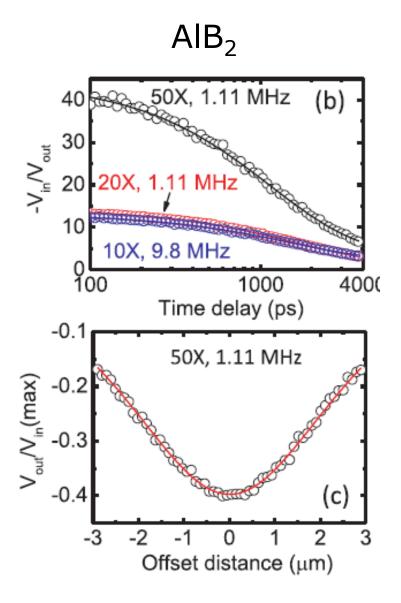


Wang et al., APL Mater. (2014)

Thermal conductivity of hexagonal borides

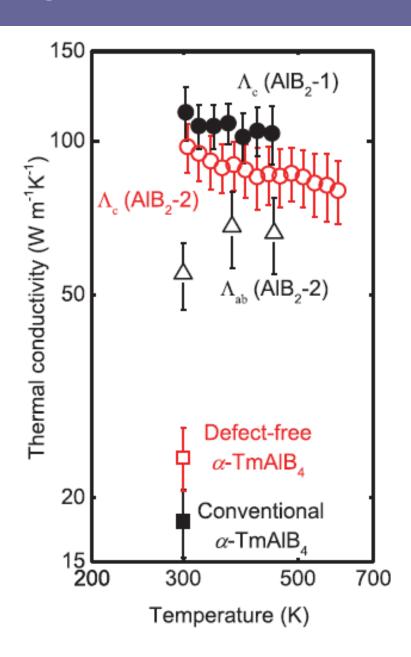
 Vary spot size, modulation frequency

 Beam offset experiment at t=-50 ps. This method of normalize minimizes error propagation.

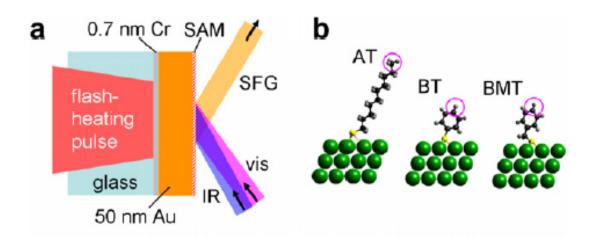


Thermal conductivity of hexagonal borides

- Could AIB₂ be used as an earth-abundant high thermal conductivity filler for composites?
- Probably not: in-plane thermal conductivity is not exceptional high.



Can we indirectly heat a Au layer through contact with a transition metal on ultrafast time scales?



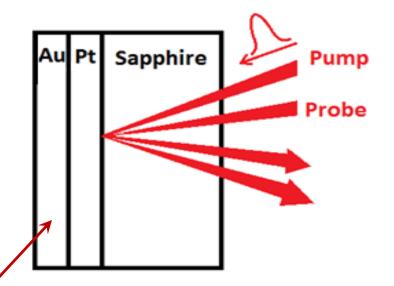
- Au provides well-defined chemistry for studies of molecular layers, however
 - Optical absorption is small so challenging to produce large temperature excursions with a laser oscillator.
 - hot-electron effects are a problem if we heat Au with amplified laser pulses.

Wang, Dlott et al., Chem. Phys. (2008)

Unfortunately, heating of the Au layer is slow because of weak electron-phonon coupling in Au

- Electronic thermal conductance of Pt/Au interface is large
 - estimate G_{ee} >10 GW m⁻² K⁻¹
- Effective conductance between Au electrons and Au phonons is not large.

g = electron-phonon coupling parameter (3×10¹⁶ W m⁻³ K⁻¹) h = Au thickness (20 nm)

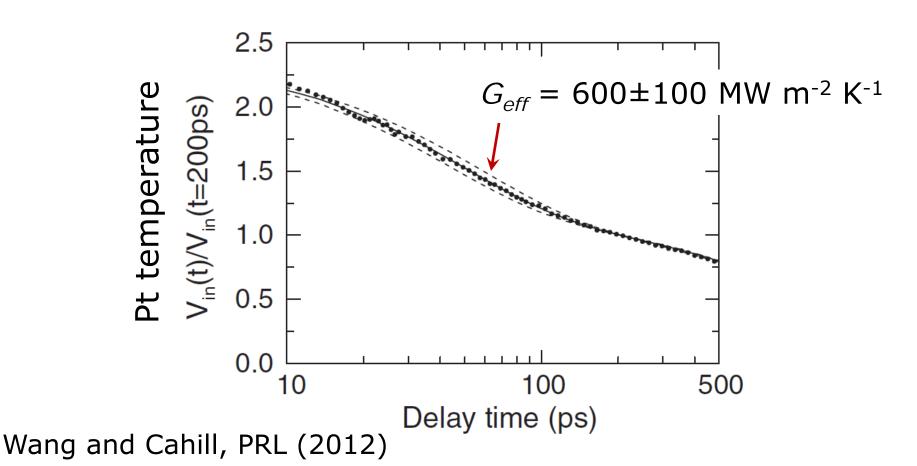


$$G_{eff} = gh = 600 \text{ MW m}^{-2} \text{ K}^{-1}$$

Unfortunately, heating of the Au layer is slow because of weak electron-phonon coupling in Au

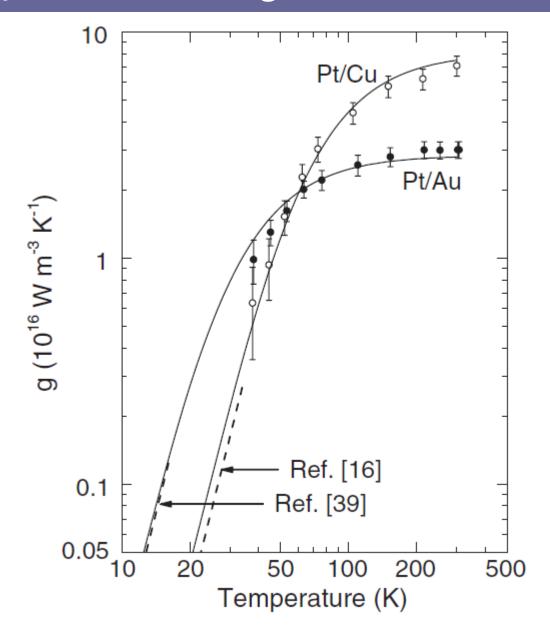
• Characteristic time scale for the heating of the Au phonons

$$\tau = \frac{C}{g} \approx 80 \text{ ps}$$



Make lemonade out of lemons: lousy way to heat Au but excellent way to measure g

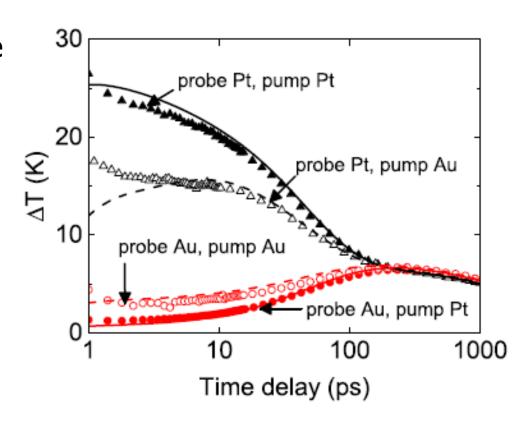
- Solid lines are the predictions of the original Kaganov "two-temperature" model of 1957
- Dashed lines are T⁴
 extrapolations of low
 temperature physics
 experiments.



Extend the story: pump and probe Au/Pt bilayer from different sides

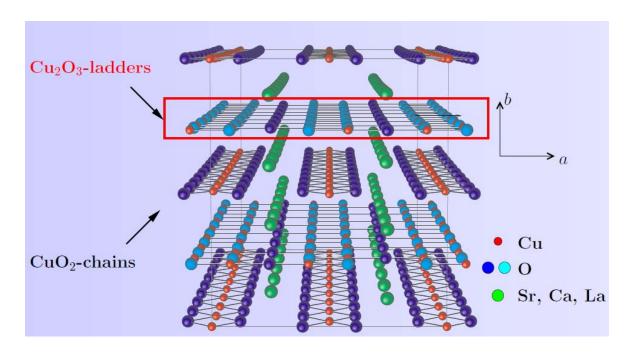
Data and transmission line modeling of Pt (23 nm)/Au(58 nm)

- Attempt to measure the Au/Pt electronic interface conductance
- Increase Au thickness to 60 nm to increase heat flux from Pt to Au
- Can only set a lower limit $G_{ee} > 5$ MW m⁻² K⁻¹



Choi et al., PRB (2014)

Magnon-phonon couplng and magnon thermal conductivity in the spin ladder Ca₉La₅Cu₂₄O₄₁

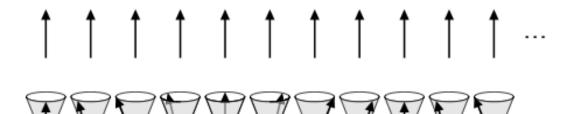


McCarron *et al.*, Mat. Res. Bull. (1988) colorized graphic by Heidrich-Meisner (2005)

Spin waves are intrinsically quantum mechanical so hard to think about in classical analogies

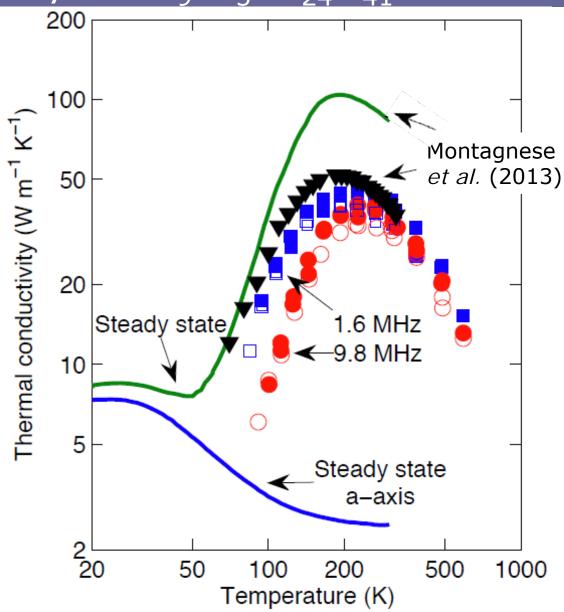
Ferromagnetic ground state

Thermally-excited spin-wave state



Wavelength

Frequency dependent spin-wave thermal conductivity in Ca₉La₅Cu₂₄O₄₁



Use a two-channel model: magnons and phonons

• Sanders and Walton (1977) analyzed the steadystate situation for the context of conventional thermal conductivity measurements. Only phonons can carry heat through the ends of the sample. $\partial T_n = \partial (-\partial T_n)$

sample.
$$C_{p}\frac{\partial T_{p}}{\partial t}-\frac{\partial}{\partial x}\left(\Lambda_{p}\frac{\partial T_{p}}{\partial x}\right)+g(T_{p}-T_{m})=0$$

$$C_{m}\frac{\partial T_{m}}{\partial t}-\frac{\partial}{\partial x}\left(\Lambda_{m}\frac{\partial T_{m}}{\partial x}\right)+g(T_{m}-T_{p})=0.$$

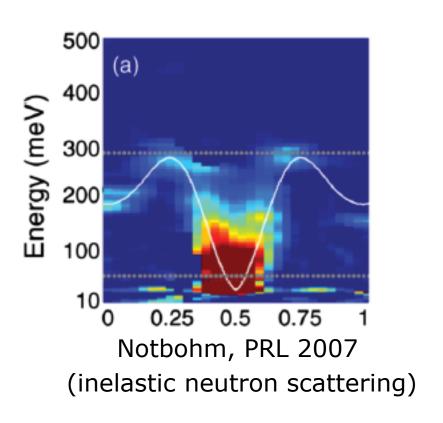
$$C_{m}\frac{\partial T_{m}}{\partial t}-\frac{\partial}{\partial x}\left(\Lambda_{m}\frac{\partial T_{m}}{\partial x}\right)+g(T_{m}-T_{p})=0.$$

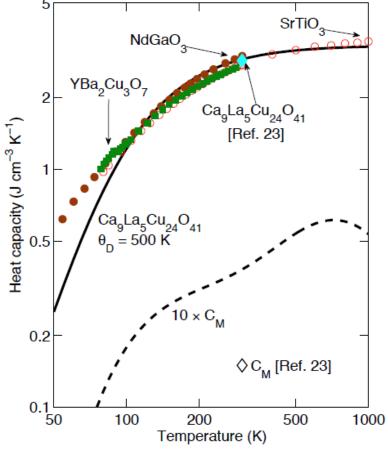
Need to fix as many parameters as possible

 Use magnon dispersion to estimate magnon heat capacity.

Lattice and magnon thermal conductivity

from Montagnese et al. (2013)

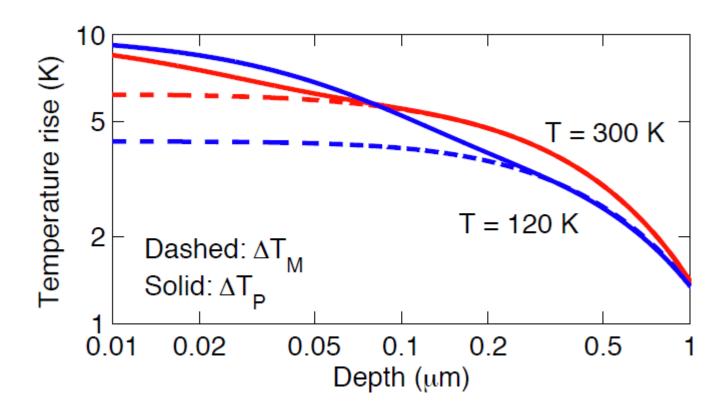




Hohensee et al., PRB (2014)

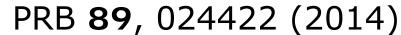
Use a two-channel model: magnons and phonons

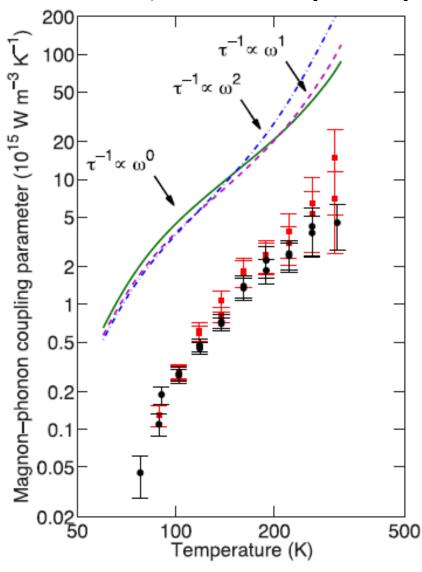
Model calculations for 10 MHz TDTR experiment.
 The coupling parameter g is adjust to get the best fit to the frequency dependent data



Magnon-phonon coupling parameter is strongly *T*-dependent

- g~10¹⁵ W m⁻³ K⁻¹ near the peak in the thermal conductivity. (30 times smaller than g for electron-phonon coupling in Au.)
- Does this coupling (and therefore magnonphonon scattering) determine the thermal conductivity near the peak?
- Is "two temperatures" too crude of a model to capture the physics?





More detail: Two-channel modeling of TDTR data

 Solution for onedimension; can generalize to threedimensions, see appendix of Wilson et al., PRB (2013)

$$\begin{bmatrix} T_1 \\ T_2 \end{bmatrix} = [X] \begin{bmatrix} B_1^- e^{-\lambda_1 z} + B_1^+ e^{\lambda_1 z} \\ B_2^- e^{-\lambda_2 z} + B_2^+ e^{\lambda_2 z} \end{bmatrix},$$

where λ^2 are the eigenvalues of the characteristic matrix

$$\begin{bmatrix} \alpha_1 & -g/\Lambda_1 \\ -g/\Lambda_2 & \alpha_2 \end{bmatrix}$$

and [X] is the associated eigenvector matrix

$$[X] = \begin{bmatrix} v_1 & v_2 \\ u_1 & u_2 \end{bmatrix}.$$

$$\begin{bmatrix} B_1^- \\ B_2^- \end{bmatrix} = [Y]^{-1} \begin{bmatrix} q_1 \\ q_2 \end{bmatrix},$$

where

$$[Y] = \begin{bmatrix} \Lambda_1 & 0 \\ 0 & \Lambda_2 \end{bmatrix} [X] \begin{bmatrix} \lambda_1 & 0 \\ 0 & \lambda_2 \end{bmatrix}.$$

Phonon-phonon non-equilibrium effects in TDTR first reported in 2007

- fix delay time and vary modulation frequency f.
- semiconductor alloys show deviation from fit using a single value of the thermal conductivity
- Change in V_{in} doesn't depend on f. V_{out} mostly depends on $(f \wedge C)^{-1/2}$

InGaAs, InGaP

InP, GaAs

O.1

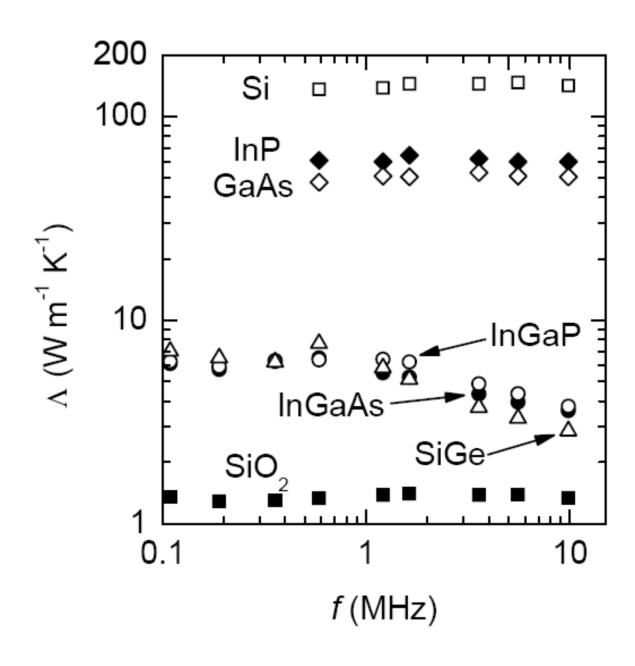
O.5 1

f (MHz)

a-SiO₂

Koh and Cahill, PRB (2007)

Same data but allow Λ to vary with frequency f



How can thermal conductivity be frequency dependent at only a few MHz?

- $2\pi f\tau << 1$ for phonons that carry significant heat. For dominant phonons, $\tau \sim 100$ ps, and $2\pi f\tau \sim 10^{-3}$.
- But the thermal penetration depth d is not small compared to the dominant mean-free-path ℓ_{dom} .

$$\mathbf{d} = \sqrt{\Lambda / \pi C f}$$

- Ansatz: phonons with $\ell(\omega) > d$ do not contribute to the heat transport in this experiment.
- True only if the "single-relaxation-time approximate" fails strongly. For single relaxation time τ , ℓ <<d because $f\tau$ << 1.

For non-equilibrium, add effusivity instead of conductivity

Consider a "two-fluid" model with

$$\Lambda_1 \approx \Lambda_2$$
 $C_1 >> C_2$

Equilibrium,

$$(\Lambda C)^{1/2} = [(\Lambda_1 + \Lambda_2)(C_1 + C_2)]^{1/2}$$

Out-of-equilibrium,

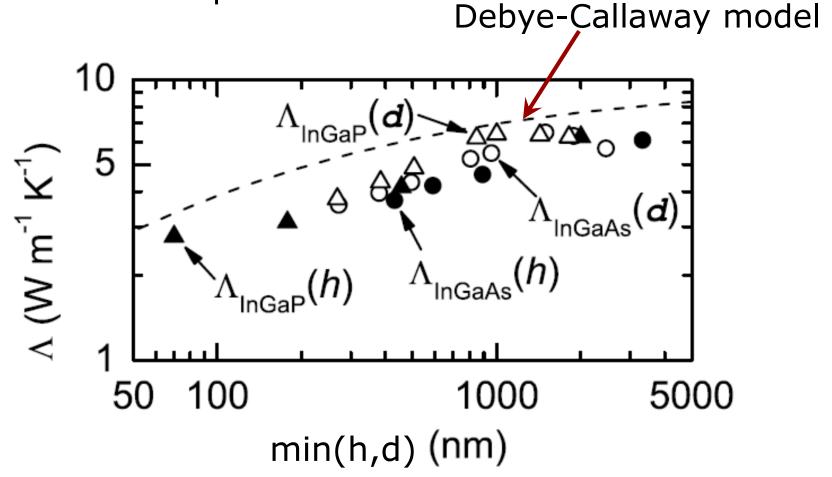
$$(\Lambda C)^{1/2} = (\Lambda_1 C_1)^{1/2} + (\Lambda_2 C_2)^{1/2}$$

 $\approx (\Lambda_1 C_1)^{1/2}$

Frequency and thickness dependence for InGaP and InGaAs

 h=film thickness; d = thermal penetration depth

$$\mathbf{d} = \sqrt{\Lambda / \pi C f}$$

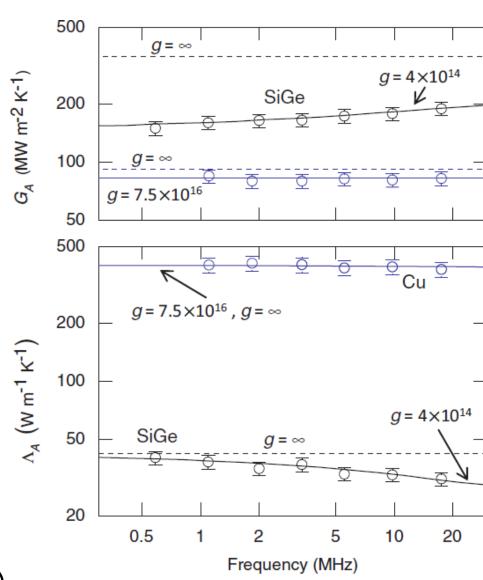


"Mean-free-path larger than thermal penetration depth" argument is probably not general; reliable only for the case a concentrated alloy (?)

- The suppression of magnon thermal conductivity as a function of frequency cannot be described in that manner even though the magnon mean-free-path is always smaller than the thermal penetration depth.
- Recent work by Rich Wilson has shown that both the apparent thermal conductivity and apparent interface conductance depend on frequency. The essence of this can be captured by a two-channel (or N-channel) model of low frequency phonons that have high thermal conductivity and low heat capacity and a thermal bath of high frequency phonons that have low thermal conductivity and high heat capacity.

Two-channel model for $Si_{99}Ge_{01}$ explains frequency dependence in both G and Λ

- Experiment and twochannel model for Al/CuO_x/Cu and Al/Si₉₉Ge₀₁
- G_A and Λ_A are what would be derived from a one-channel model applied to the data.
- Solid and dashed lines are the predictions based on a two-channel model



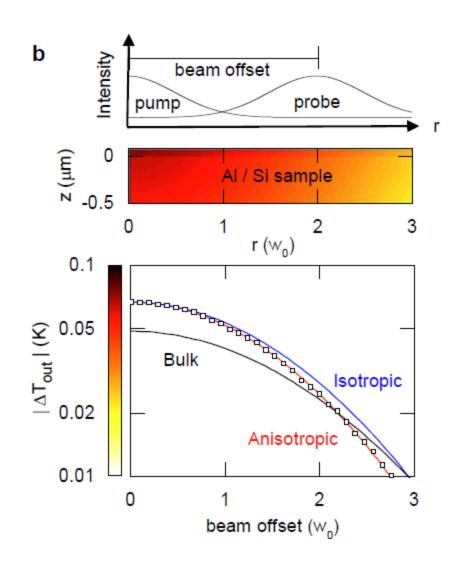
Wilson and Cahill, PRB (2013)

Beam-offset measurements on Si reveal anisotropy in apparent thermal conductivity

- Spot size $w_0 = 1.05 \mu m$.
- Measure V_{out} at negative delay time as a function of beam offset.
- Apparent thermal conductivity is anisotropic, radial component is reduced by nearly a factor of 2,

$$\Lambda_r \approx 80 \text{ W m}^{-1} \text{ K}^{-1}$$

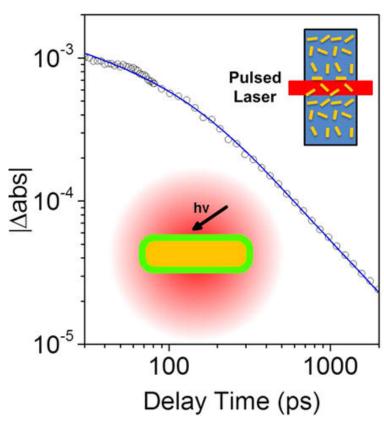
 $\Lambda_z \approx 140 \text{ W m}^{-1} \text{ K}^{-1}$



Wilson and Cahill, submitted

Thermoreflectance is not the only ultrafst optical thermometry we can use to study nanoscale thermal science

- Transient adsorption using plasmon resonances of Au nanostructures
- Sensitive to both the temperature of the Au and the surrounding dielectric. Learning how to separate the effects.
 - At a wavelength near the peak absorption, only the Au temperature is important.
 - Signal from surrounding material can be isolated by realizing that the surrounding material cannot heat instantaneously.



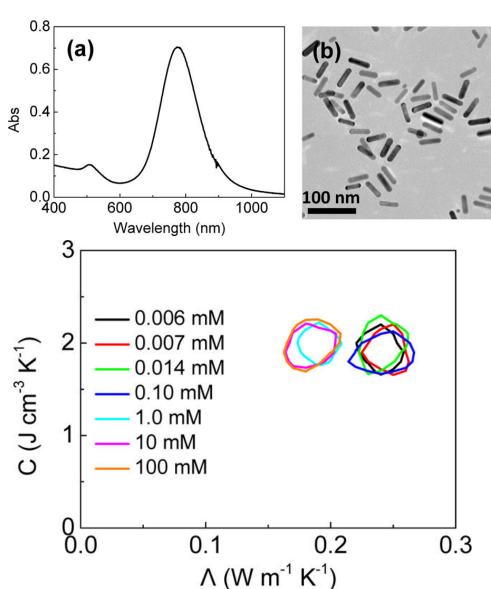
Huang et al, ACS Nano (2012)

Ultrafast thermal analysis of surfactant layers surrounding Au nanorods

 Aspect ratio tuned so that the absorption peak can be aligned with the Ti:sapphire laser wavelength.

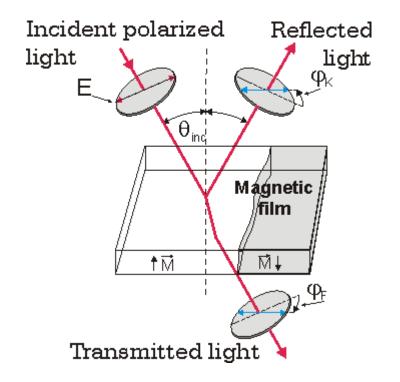
 Heat capacity and thermal conductivity of CTAB surfactant layers as a function of CTAB concentration in solution.

Huang et al, ACS Nano (2012)

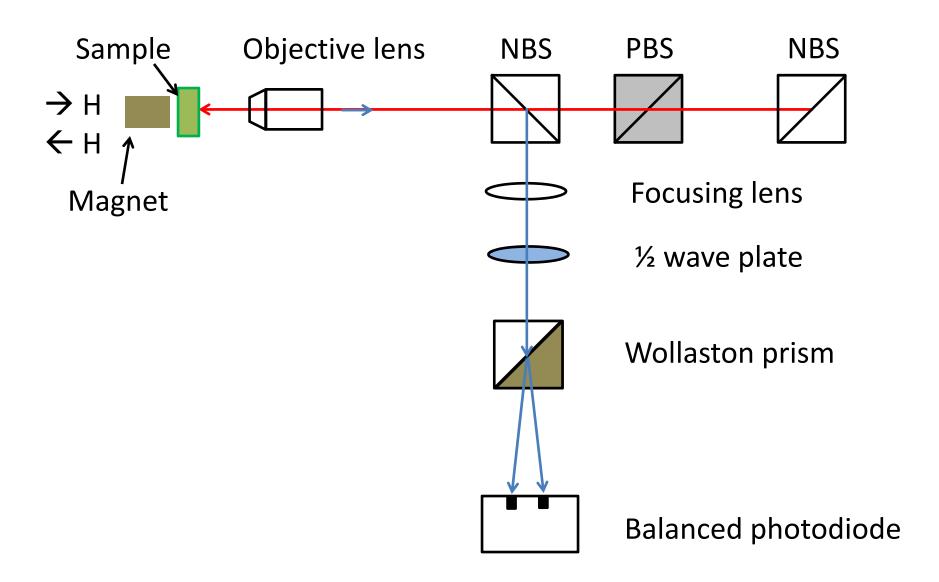


Thermoreflectance is not the only ultrafst optical thermometry we can use to study nanoscale thermal science

- Magnetic-optic Kerr effect
 - Polarization rotates upon reflection from a ferromagnetic material. Perpendicular magnetization simplifies the optical design

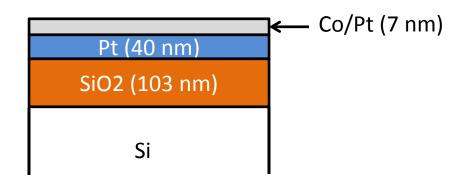


Schematic of TR-MOKE Setup (Reflectance Configuration)

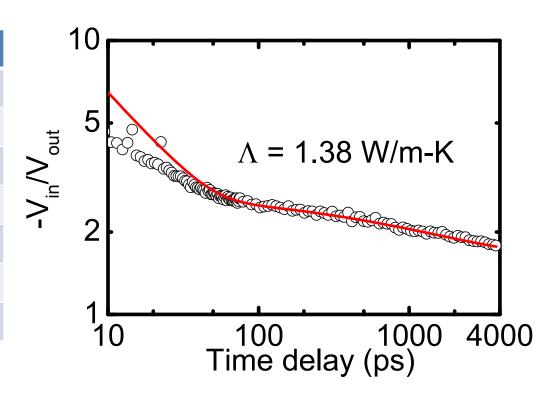


Validation Measurement

Co/Pt+Pt on SiO2/Si reference sample



Layer	Λ	С	h
	[W/m-K]	[J/cm^3-K]	[nm]
Co/Pt	20	3.15	7
Pt	40	2.84	40
G	0.2	0.1	1
SiO2	1.38 (fit)	1.62	103
G	0.1	0.1	1
Si	142	1.64	1e6



Summary

- Improvements to sensitivity to in-plane thermal conductivity will require smaller spot-sizes and lower thermal conductance transducer. Both of these goals might be best achieved by time-resolved magneto-optic Kerr effect. (Work in progress).
- Two-channel model is a significant advance that enables quantitative modeling of coupled electron-phonon transport in metals and magnon-phonon transport in quantum anti-ferromagnetic cuprates.
- Phonon-phonon non-equilibrium effects are complicated.
 Simple interpretation in terms of phonon-mean free paths and thermal penetration depths might be limited to concentrated alloy non-metallic crystals.